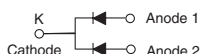


High Current Density Surface Mount Schottky Barrier Rectifier

eSMP™ Series



TO-277A (SMPC)



FEATURES

- Very low profile - typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal impedance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

AUTOMOTIVE
GRADE
Available



RoHS
COMPLIANT
HALOGEN
FREE

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 6.0 A
V_{RRM}	40 V
I_{FSM}	150 A
E_{AS}	20 mJ
V_F at $I_F = 6.0$ A	0.40 V
T_J max.	125 °C

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	SS12P4C	UNIT
Device marking code		S124C	
Maximum repetitive peak reverse voltage	V_{RRM}	40	V
Maximum average forward rectified current (fig. 1) ⁽¹⁾	$I_{F(AV)}$	12	A
		6.0	
Maximum average forward rectified current ⁽²⁾	$I_{F(AV)}$	3.5	A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150	A
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH per diode	E_{AS}	20	mJ
Peak repetitive reverse current at $t_p = 2$ μ s, 1 kHz, at $T_J = 25$ °C per diode	I_{RRM}	1.0	A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 125	°C

Notes

⁽¹⁾ Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink

⁽²⁾ Free air, mounted on recommended copper pad area

SS12P4C

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**ELECTRICAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	$I_F = 1\text{ A}$	$V_F^{(1)}$	0.34	-	V
	$I_F = 3\text{ A}$		0.40	-	
	$I_F = 6\text{ A}$		0.46	0.52	
	$I_F = 1\text{ A}$		0.24	-	
	$I_F = 3\text{ A}$		0.31	-	
	$I_F = 6\text{ A}$		0.40	0.45	
Reverse current per diode	Rated V_R	$I_R^{(2)}$	129	500	μA
			11.9	25	mA
Typical junction capacitance per diode	4.0 V, 1 MHz	C_J	400	-	pF

Notes(3) Pulse test: 300 μs pulse width, 1 % duty cycle(4) Pulse test: Pulse width $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	SS12P4C	UNIT
Typical thermal resistance	$R_{\theta JA}^{(1)}$	100	$^{\circ}\text{C/W}$
	$R_{\theta JM}^{(2)}$	3	

Notes(1) Free air, mounted on recommended copper pad area. Thermal resistance $R_{\theta JA}$ - junction to ambient.(2) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink. Thermal resistance $R_{\theta JM}$ - junction to mount.**ORDERING INFORMATION** (Example)

PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SS12P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel
SS12P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel
SS12P4CHM3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
SS12P4CHM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel

Note

(1) Automotive grade

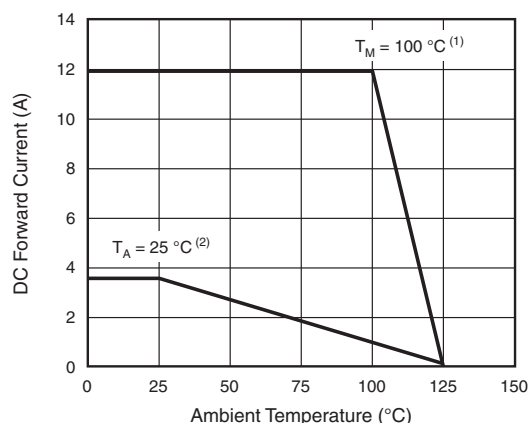
RATINGS AND CHARACTERISTICS CURVES($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

Notes

- Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink, T_M measured at the terminal of cathode band ($R_{\theta JM} = 3\text{ }^{\circ}\text{C/W}$)
- Free air, mounted on recommended copper pad area ($R_{\theta JA} = 100\text{ }^{\circ}\text{C/W}$)

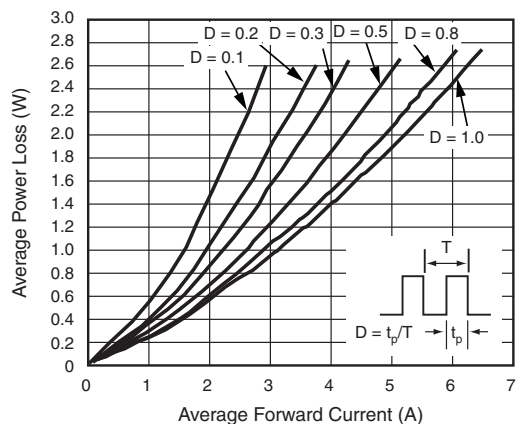


Fig. 2 - Forward Power Loss Characteristics Per Diode

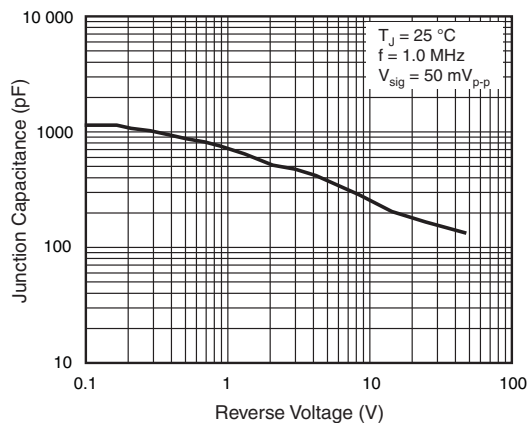


Fig. 5 - Typical Junction Capacitance Per Diode

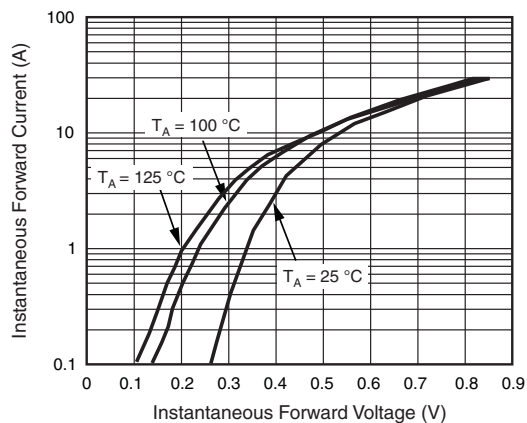


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

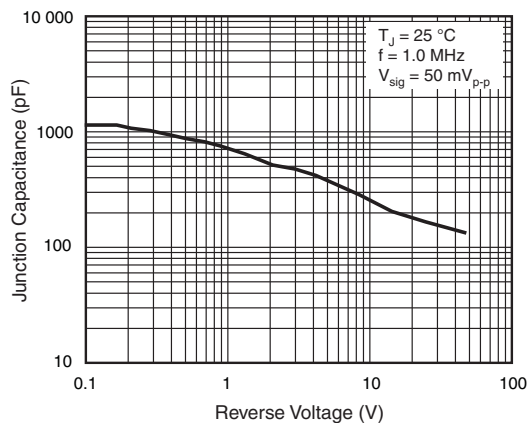


Fig. 6 - Typical Transient Thermal Impedance Per Diode

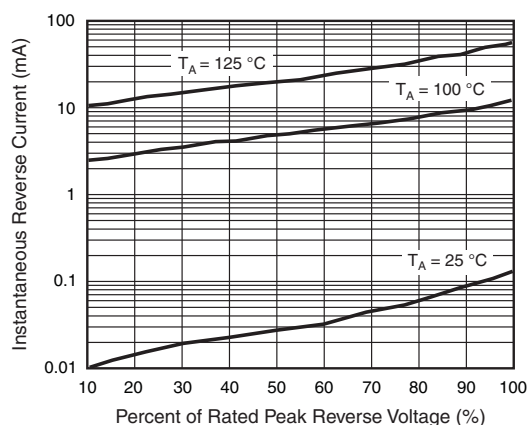
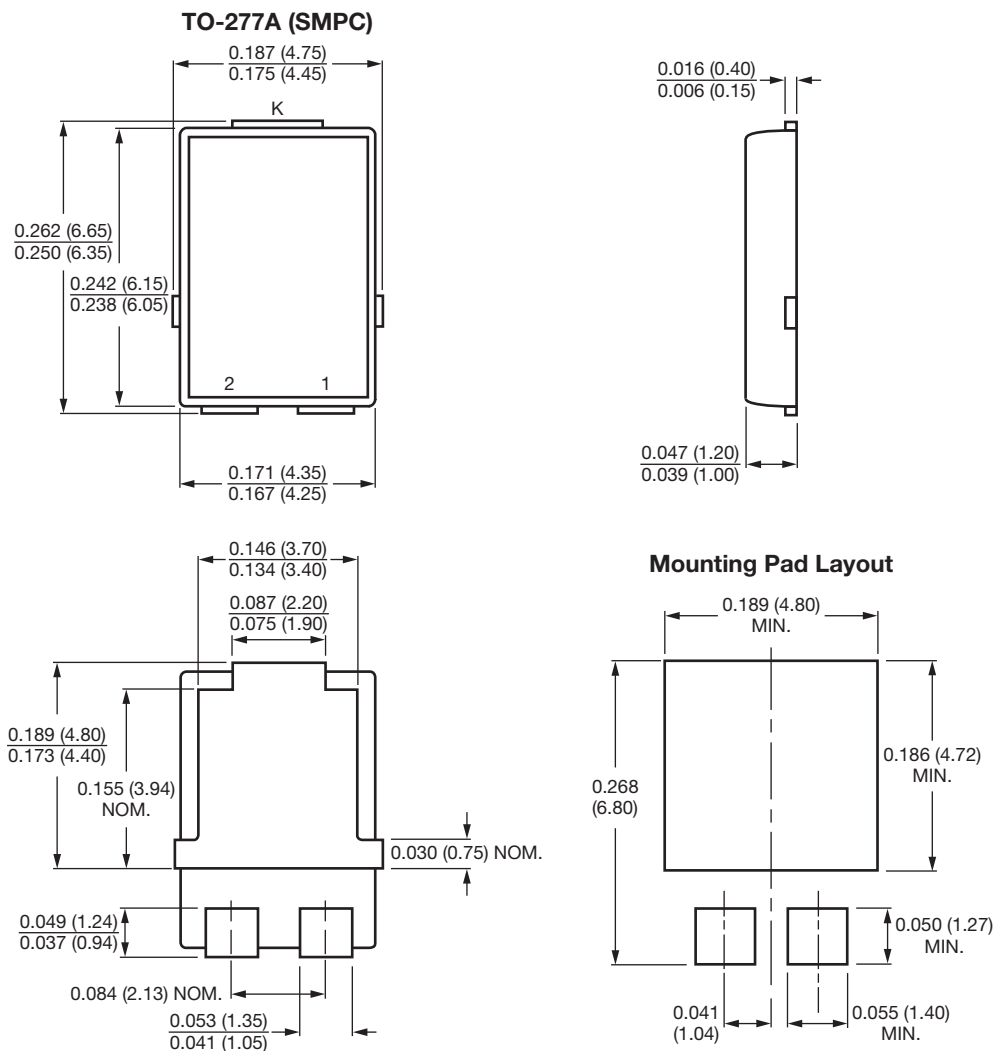


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

SS12P4C

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**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

Conform to JEDEC TO-277A



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